NSN 5962-01-363-3446

Memory Microcircuit - Page 1 of 1



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Maximum Power Dissipation Rating:

330.0 milliwatts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Burn in and electrostatic sensitive and monolithic and programmed and ultraviolet erasable

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Complementary-metal oxide-semiconductor logic

Input Circuit Pattern:

25 input

Current Rating Per Characteristic:

60.00 milliamperes forward current, nonrepetitive, peak total value microamperes

Terminal Surface Treatment:

Solder

Product Name:

128k x 8 eprom

Voltage Rating And Type Per Characteristic:

7.0 volts power source

Memory Device Type:

Eprom

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

32 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

A458a0